

## PV85L0.5ASTA-0-1-01 Series 850 nm VCSELs

PD-LD Inc. offers a variety of standard Vertical Cavity Surface Emitting Lasers (VCSELs) in ready to use fiber coupled packages. Packaging options include Receptacle style housings such as ST, FC and SC as well as fiber pigtailed co-axial assemblies. VCSELs are typically used with multi-mode optical fiber and may be specified for coupling to 50  $\mu\text{m}$ , 62.5  $\mu\text{m}$ , 100  $\mu\text{m}$  and 200  $\mu\text{m}$  core optical fibers. VCSELs may also be fiber coupled to single mode fibers with 5, 7 or 9  $\mu\text{m}$  core diameters. Units built with fiber pigtailed are available terminated with optical connectors. Specialty fiber sizes may be available upon request.

VCSEL devices operating at 850 nm may be specified with or without internal monitor detectors for stabilizing the optical power output using feedback. VCSELs have inherently narrow optical spectrums of 0.5 nm FWHM. Maximum rise and fall times of 0.3 nsec make them ideal for high speed modulation, but the devices may also be operated in CW mode.



### Features 850 nm VCSELs

- Low Operating Current, 6 to 12 mA typ.
- High Speed  $\geq$  1GHz
- Hermetically Sealed optical subassembly
- Five Different Laser/Photodiode Polarities available
- Power monitor diode available
- Available in TOSA housings for transceiver packaging

### Pigtailed Devices

PVWWWPPPFCCB-0-V-LL

PV85L0.5ASTA-0-1-01

**P** = PD=LD Product

**V**= Vertical Cavity Surface Emitting Laser (VCSEL)

**WWW**= Wavelength and Device Code

85L indicates 850nm center wavelength with 3 lead pin-out

**PPP**= Fiber Coupled Optical Power

0.5 indicates 0.5mW

**F**= Fiber Type

A indicates 200 $\mu\text{m}$  Core Hard Clad Silica Fiber with 0.37NA

3 indicates 62.5 $\mu\text{m}$  core MMF 0.28NA

**CC**= Connector Type

ST indicates ST/PC Optical Connector

**RR**= Receptacle Type, ST7 low profile ST style

**B**= Mounting Bracket

A indicates No Bracket

**O**= Orientation of Leads with respect to mounting bracket or Receptacle

A indicates no bracket so not applicable

**V**= Version

"1" indicates unit built and test with 200 $\mu\text{m}$  core 0.37NA MMF

**LL**= Length of optical pigtail

01 indicates 1m

### Receptacle Devices

PVWWWPPPRRF-O-V

PV85L0.5ST73-Z-0

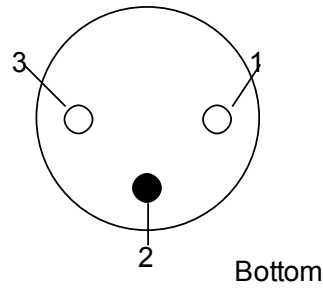
<sup>1</sup>Examples only; most device/package combinations available.

Changes to specifications may be made without notice.

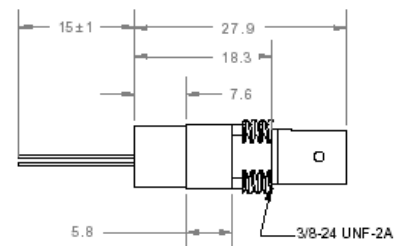
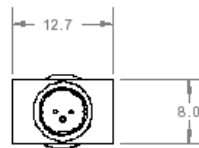
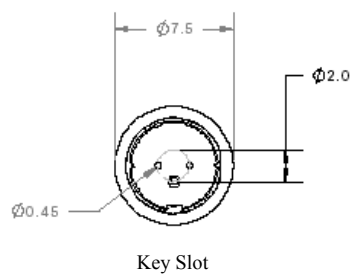
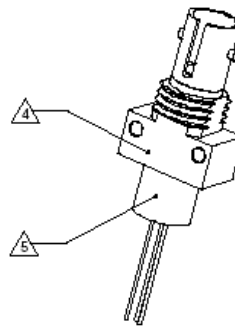
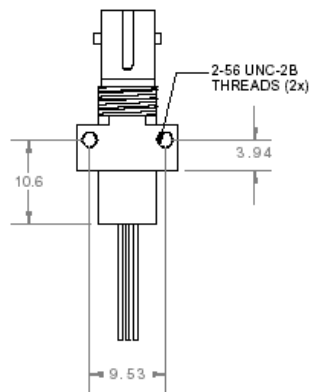
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3 Lead VCSEL PIN-OUT



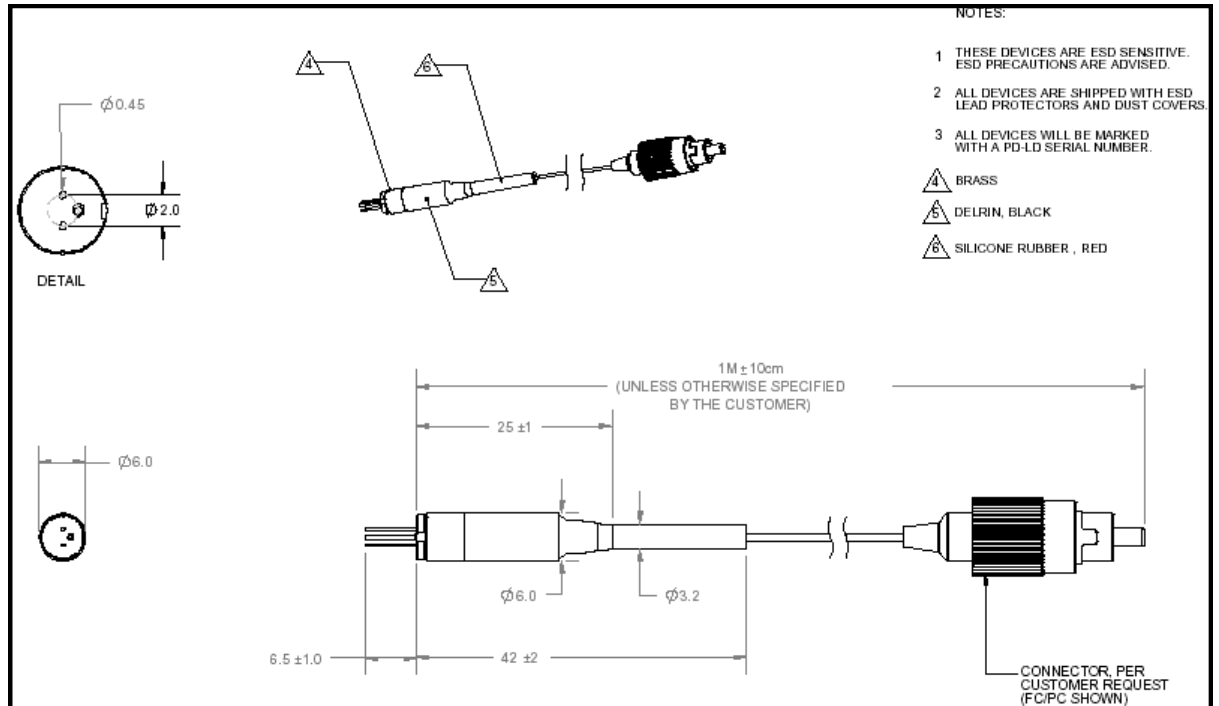
3 Lead VCSEL	
Pin-Out	“85L”
Pin #1	LD <sub>cathode</sub>
Pin #2	PD <sub>cathode</sub> LD <sub>Anode</sub>
Pin #3	PD <sub>Anode</sub>



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### Mechanical Dimensions for Pigtailed Packages



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### PV85L0.5ASTA-0-1-01 Series 850 nm VCSELS

Absolute Maximum Ratings			
Parameter	Symbol	Value	Unit
VCSEL Continuous Average Current	$I_{op}$	15	mA
VCSEL Peak forward Current with pulse widths < 1 usec	$V_{pk}$	20	mA
VCSEL Reverse Voltage	$V_R$	5	V
Operating Temperature	$T_{OPR}$	-10 to 70	°C
Storage Temperature	$T_{STR}$	-40 to 85	°C
Soldering Temperature	$T_{Solder}$	260	°C (10 seconds max)

ELECTRICAL-OPTICAL CHARACTERISTICS						
VCSEL Parameter	Test Condition	Symbol	Min	Typ	Max	Units
Peak Operating Current	Adjustable to Establish Power	$I_{PEAK}$		12	20	mA
Optical Power Output	$I = 12mA$	$P_o$	0.5		2	mW
Threshold Current		$I_{TH}$	2	3.5	6	mA
Threshold Current Temperature Variation	$T_A = 0$ to 70 degree C	$\Delta I_{TH}$	-1.5		1.5	mA
Slope Efficiency	$P_o = 0.5mW$	$\eta$	0.05	0.15	0.4	mW/mA
Slope Efficiency Temperature Variation	$T_A = 0$ to 70 degree C	$\Delta\eta/\Delta T$		-0.5		%/degC
Peak Wavelength	$I = 12mA$	$\lambda_p$	830	850	860	nm
Wavelength Temperature Variation	$I = 12mA$	$\Delta\lambda_p/\Delta T$		0.06		nm / deg C
Spectral Bandwidth	$I = 12mA$	$\Delta\lambda$			0.85	nm
Laser Forward Voltage	$I = 12mA$	$V_F$	1.6	1.8	2.2	V
Laser Reverse Voltage	$I_R = 10\mu A$	$BVR_{ID}$	5	10		V
Series Resistance	$I = 12mA$	$R_S$	18	25	40	Ohms
Photodiode Parameters	Test Condition	Symbol	Min	Typ	Max	Units
Monitor Current	$P_o = 0.5mW$	$I_{PD}$	0.01		0.06	mA
Dark Current	$P_o = 0mW, R = 3V$	$I_D$			20	nA
PD Reverse Voltage	$P_o = 0mW, R = 3V$	$BVR_{PD}$	30	115		V
PD Capacitance	$V_R = 3V$			40	55	pF

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